

Gate modulation of the hole singlet-triplet qubit frequency in germanium

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- all-electrical qubit control
- strong spin-orbit coupling
- site-dependent g-tensor
- S-T₋ qubit frequency strong function of barrier gate voltage
- an order of magnitude change of g-factor with 12 mV change of the gate voltage
- strain profile



Device



- Ge/SiGe heterostructure
- 2D hole gas accumulated using global top gate
- P₁, P₂ plungers
- V_B controls the coupling between the dots
- all experiments done at (1,1)-(0,2)
- SET change sensing
- detuning:

$$\epsilon = \alpha_2 V_{P2} - \alpha_1 V_{P1}$$





• $S_{02} - S_{11}$ hybridization due to the tunnel coupling

 $|\mathsf{S}\rangle = \sin\left(\Omega/2\right)|\mathsf{S}_{02}\rangle - \cos\left(\Omega/2\right)|\mathsf{S}_{11}\rangle$

•
$$\Omega = \arctan\left(\frac{2\sqrt{2}t_c}{\epsilon}\right)$$
 - mixing angle

- three triplet states
- permanent magnet on the PCB |B| = 4.6 mT
 - lifts the degeneracy of triplet states
 - 4.4 mT in-plane field
 - 1.2 mT out-of-plane field
- splits $|T_{-}\rangle$ and $|T_{0}\rangle$ by \overline{E}_{z}
- initialization into S(0,2) at M
- pulse P1 and P2, separate holes: mixture of $|S\rangle = \frac{1}{\sqrt{2}}(|\uparrow\downarrow\rangle |\downarrow\uparrow\rangle)$ and $|T_{-}\rangle = |\downarrow\downarrow\rangle$
- evolution for t_E at ϵ_P





- qubit frequency: $hf = \Delta E_{ST}$
- large detuning: \overline{E}_z
- minimum at S-T₋ anticrossing: $2\Delta_{ST_-}$
- minimum chevron pattern at 1 meV
- { $|S\rangle$, $|T_{}\rangle$ } dynamics

$$H = \begin{pmatrix} -J(\epsilon) & \Delta \\ \Delta & -\overline{E}_z \end{pmatrix}$$

- exchange energy: $J(\epsilon) = -\frac{\epsilon}{2} + \sqrt{\frac{\epsilon^2}{4} + 2t_c^2}$ energy difference between |S> and |T₀>
- S-T₋ coupling: $\Delta = |\Delta_{so} \sin\left(\frac{\Omega}{2}\right) + g_a \mu_B B \cos\left(\frac{\Omega}{2}\right)|$
 - spin-orbit splitting
 - effective Zeeman splitting, anisotropy of the g-tensors

• | T_) and |T_) slitting:
$$\overline{E}_z = \overline{g} \mu_B B$$

• average g-factor





- qubit frequency: $f = \frac{1}{h}\sqrt{(J \overline{E}_z)^2 + (2\Delta)^2}$
- at S-T₋ anticrossing: $J = \overline{E}_z$, X rotations
- large detunings: $J \rightarrow 0$, z-axis rotations
- { $|S\rangle$, $|T_{}\rangle$ } dynamics

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- readout at M using Pauli spin blockade
- reset at R before repeating







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- fit T2*: $P = Ae^{-(t/T_2^*)^2} \cos(\omega t + B) + Ce^{-t/D} + E$
 - maximum in T2* at 1 meV, residual decay: $\delta\Delta$ rms = 0.8 neV
 - decay at the large detuning: δEz,rms = 3 neV





∆ا_{SET} (a.u.)

-20

-25

-30

2 4

6 8

 $t_{\sf wait}^{}$ (μ s)



 $t_{\rm wait}$

10 12 14 16 18 20

- T1 varying wait time at the readout position $\varepsilon_{\rm r}$
- fit T1 using: $P = Ae^{-(t/T_1)} + B$
- T1 = $17.2 \pm 3.2 \ \mu s$







- dramatic change of f as function of VB
- extract \overline{g} from $f \sim \overline{E}_z/h$ at large detunings
- extract $\Delta_{ST_{-}}$ from $2\Delta_{ST_{-}}/h$ at minimum frequency





Conclusion

- coherent oscillations between S and T-
- dephasing time T2* = 600 ns
- relaxation time T1 = 17.2 us
- strain induced change of qubit frequency